

DSA612

Two-Output Low Power MEMS Clock Generator for Automotive

Features

- · Automotive AEC-Q100 Qualified
- MEMS-Based Clock Generator Eliminates the Need for External Crystal or Reference Clock
- Two LVCMOS Output Clocks: 2 kHz to 100 MHz
- Low Power Consumption: ~5 mA (Both Outputs Active)
- Wide Supply Voltage Range: 1.71V to 3.63V
- Ultra-Small Package Sizes:
 - 1.6 mm x 1.2 mm
 - 2.0 mm x 1.6 mm
 - 2.5 mm x 2.0 mm
- High Frequency Stability: ±20 ppm, ±25 ppm, ±50 ppm
- · Wide Temperature Range:
 - Automotive (Grade 1): -40°C to +125°C
 - Automotive (Grade 2): -40°C to +105°C
 - Automotive (Grade 3): -40°C to +85°C
- · Excellent Shock and Vibration Immunity:
 - Shock: Qualified to MIL-STD-883E Method 2002.3. Test Condition G (30,000g)
 - Vibration: Qualified to MIL-STD-883E Method 2007.2, Test Condition C (70g)
- Spread Spectrum Clock Generation for EMI Reduction
- · High Reliability
- Lead-Free and RoHS-Compliant

Applications

- · Automotive Infotainment
- · Automotive ADAS, Surround View Cameras
- · In-Vehicle Networking, CAN bus, Ethernet

General Description

The DSA612 is a MEMS low power, ultra-small footprint, crystal-less family of clock generators. The DSA612 family is factory-configurable and generates up to two independent LVCMOS outputs. Each output can be configured to generate any frequency from 2 kHz to 100 MHz. The two-output DSA612 MEMS oscillators are excellent choices for use as clock references in automotive applications in which small size, low power consumption, and long-term reliability are paramount. The family of devices is AEC-Q100 qualified.

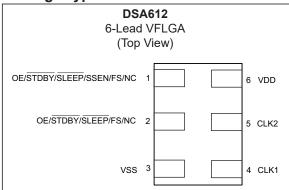
The DSA612 implements Microchip's proven PureSilicon™ MEMS technology to provide low jitter and high stability across a wide range of supply voltages and temperatures. By eliminating the external quartz crystal, Microchip's crystal-less™ clock generators significantly enhance reliability and accelerate product development.

The DSA612 has two control inputs that can be configured to function as output enable/disable, standby, sleep, spread spectrum enable, and frequency select. The DSA612 is available in space saving 6-pin, 1.6 mm x 1.2 mm, 2.0 mm x 1.6 mm, and 2.5 mm x 2.0 mm VFLGA plastic packages.

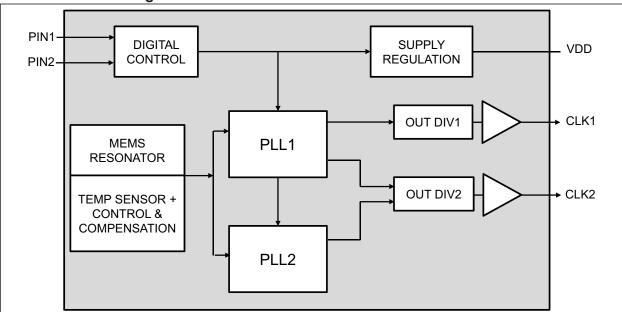
The DSA612 spread spectrum function includes both center and down spreading, and is explained further in the Spread Spectrum section.

The DSA612 is a highly configurable device and is factory programmed to meet the customer's needs. Microchip's ClockWorks Configurator must be used to choose the necessary options, create the final part number, data sheet, and order samples.

Package Type



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	
Input Voltage	
	4 kV
	400V
` '	2 kV

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 1.8V ±5% to 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Supply Voltage	V_{DD}	1.71	_	3.63	V	Note 1
Active Supply Current	I _{DD}	_	5	6	mA	f _{CLK1} = 27 MHz, f _{CLK2} = 25 MHz, V _{DD} = 1.8V, No Load
Active Supply Current (Sleep Mode, 1 PLL Off)	I _{DDSL}		3	_	mA	$CLK2 = SLEEP, f_{CLK1} = 25 MHz,$ $V_{DD} = 1.8V, No Load$
Active Supply Current (32.768 kHz Output Only)	I _{DD32k}		1.4	_	mA	CLK2 = SLEEP, f _{CLK1} = 32.768 kHz, V _{DD} = 1.8V, No Load
Standby Supply Current,	1	_	1.0	_		V _{DD} = 1.8V/2.5V
Note 2	ISTDBY	_	1.5	_	μA	V _{DD} = 3.3V
		_	_	±20		
Frequency Stability, Note 3	Δf	_	_	±25	ppm	All temperature ranges
		_	_	±50		
Aging	Δf	_	_	±5	ppm	1st year @ +25°C
Aging	Δι	_	_	±1		Per year after the first year
Startup Time	t _{SU}	_	_	1.5	ms	From 90% V _{DD} to valid clock output, T = +25°C
Input Logic Levels, Note 4	V _{IH}	0.7 x V _{DD}	_	_	V	Input logic high
Imput Logic Levels, Note 4	V _{IL}	_	_	0.3 x V _{DD}	V	Input logic low
Output Disable Time	t _{DA}		_	200 + 2 Periods	ns	Note 5
Output Enable Time	t _{EN}	_	1.0	_	μs	Note 6
Enable Pull-Up Resistor		_	300	_	kΩ	Note 7
Output Logic Levels	V _{OHY}	0.8 x V _{DD}	_	_	V	I = 6 mA (high drive) or I = 3 mA (standard drive)
Output Logic Levels	V _{OLY}	_	_	0.2 x V _{DD}	V	I = -6 mA (high drive) or I = -3 mA (standard drive)

DSA612

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 1.8V ±5% to 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
	4 /4		1.2	2.0	ns	Standard drive 20% - 80% C _L = 10 pF, V _{DD} = 1.8V
Output Transition Time, Rise	t _{RY1} /t _{FY1}	_	0.6	1.2	ns	Standard drive 20% - 80% C _L = 10 pF, V _{DD} = 2.5V/3.3V
Time/Fall Time	t/t	_	1.0	1.5	ns	High drive 20% - 80% C_L = 15 pF, V_{DD} = 1.8 V
	t _{RY2} /t _{FY2}	_	0.5	1.0	ns	High drive 20% - 80% C_L = 15 pF, V_{DD} = 2.5V/3.3V
Frequency	f0	0.002		100	MHz	_
Output Duty Cycle	SYM	45	_	55	%	_
	J _{PER}	ı	17			f _{CLK1} = 24 MHz, f _{CLK2} = 27 MHz, V _{DD} = 1.8V
Period Jitter, RMS			14		ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, V_{DD} = 3.3V
		1	9	1		f_{CLK1} = 27 MHz, f_{CLK2} = 27 MHz or 32.768 kHz, V_{DD} = 3.3V
			120			f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, V_{DD} = 1.8V
Period Jitter, Peak-to-Peak	J _{PER}		100		ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, V_{DD} = 3.3V
			80			f _{CLK1} = 27 MHz, f _{CLK2} = 27 MHz or 32.768 kHz, V _{DD} = 3.3V
		_	105	_		f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, V_{DD} = 1.8V
Cycle-to-Cycle Jitter (peak)	J _{Cy-Cy}	_	90	_	ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, V_{DD} = 3.3V
		_	70	_		f_{CLK1} = 27 MHz, f_{CLK2} = 27 MHz or 32.768 kHz, V_{DD} = 3.3V

Note 1: V_{DD} pin should be filtered with a 0.1 μ F capacitor.

- 2: Excludes input pull-up current.
- 3: Includes frequency variations due to initial tolerance, temperature, and power supply voltage.
- **4:** Input waveform must be monotonic with rise/fall time < 10 ms.
- 5: Output disable time takes up to two Periods of the output waveform, plus 200 ns.
- **6:** For parts configured with OE, not Standby.
- **7:** Output is enabled if pad is floated or not connected.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature	TJ	_	_	+150	°C	_
Storage Temperature Range	T _S	-55	_	+150	°C	_
Lead Temperature	_	_	+260	_	°C	Soldering, 40s

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The DSA612 is a highly configurable device and can be factory programmed in many different ways to meet the customer's needs. Microchip's ClockWorks Configurator http://clockworks.microchip.com/Timing/ must be used to choose the necessary options, create the final part number, data sheet, and order samples. The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: DSA612 PIN FUNCTION TABLE

Pin Number	Pin Name	Description
	OE	Output Enable: H = Active, L = Disabled (High Impedance).
	STDBY	Standby: H = Device is active, L = Device is in standby (Low Power Mode).
	FS	Frequency Select: H = Output Frequency 1, L = Output Frequency 2.
1	SLEEP	Sleep: H= Output Enabled, L= Output and associated PLL Disabled.
	SSEN	Spread Spectrum: H = Enabled, L = Disabled.
	NC	Non-functional, do not connect.
	OE	Output Enable: H = Active, L = Disabled (High Impedance).
	STDBY	Standby: H = Device is active, L = Device is in standby (Low Power Mode).
2	FS	Frequency Select: H = Output Frequency 1, L = Output Frequency 2.
	SLEEP	Sleep: H= Output Enabled, L= Output and associated PLL Disabled
	NC	Non-functional, do not connect.
3	VSS	Ground.
4	CLK1	Factory configurable LVCMOS clock output 1: 2 kHz to 100 MHz, standard drive or high drive.
5	CLK2	Factory configurable LVCMOS clock output 2: 2 kHz to 100 MHz, standard drive or high drive.
6	VDD	Power Supply: 1.71V to 3.63V.

An explanation of the different options listed in Table 2-1 follows:

2.1 Pin 1 and Pin 2

These are control pins and each may be configured to fulfill one of six different functions. If not actively driven, a 10 k Ω pull-up resistor is recommended.

2.1.1 OUTPUT ENABLE (OE)

Both pin 1 and pin 2 may be configured as Output Enable. Either or both outputs may be turned on and off according to the state of the pins.

2.1.2 STANDBY

Either pin 1 or pin 2 (but not both) may be configured as standby. When the pin is low, both outputs will be off and the device will enter a low power mode.

2.1.3 SLEEP

Either pin 1 or pin 2 (but not both) may be configured as sleep. When the pin is low, one phase lock loop (PLL) will shut down, enabling power saving. Any output driven by that PLL will be turned off.

2.1.4 SPREAD SPECTRUM ENABLE (SSEN)

Only pin 1 may be configured as SSEN. When the pin is high, the associated output will be spread in frequency. When the pin is low, no spreading will occur.

2.1.5 FREQUENCY SELECT (FS)

Both pin 1 and pin 2 may be configured as FS. Each output may be set to one of two pre-programmed frequencies (four pre-programmed frequencies in total).

2.1.6 NC

Both pin 1 and pin 2 may be configured as NC. In this case, the pins are non-functional and the device is programmed and fixed according to the choices in ClockWorks Configurator.

2.2 Pins 3 through 6

Pins 3 and 6 are the supply terminals, V_{SS} and V_{DD} respectively. Pins 4 and 5 are the two clock outputs, CLK1 and CLK2, respectively. CLK1 and CLK2 outputs are programmable to Standard and High Drive strengths settings through ClockWorks Configurator.

3.0 SPREAD SPECTRUM

Spread spectrum is a slow modulation of the clock frequency over time. The PLL inside the MEMS oscillator is modulated with a triangular wave at 33 kHz. With such a slow modulation, the peak spectral energy of both the fundamental and all the harmonics is spread over a wider frequency range. This significantly reduces peak energy density, thus providing an EMI reduction. The triangular wave is chosen because of its flat spectral density.

The DSA612 MEMS oscillator family offers several modulation options: the spreading is either center spread or down spread with respect to the clock frequency. Center spreading ranges from $\pm 0.25\%$ to $\pm 2.5\%$, while down spreading ranges from -0.25% to -3%.

If the clock frequency is 100 MHz and center spreading with $\pm 1\%$ is chosen, the output clock will range from 99 MHz to 101 MHz. If down spreading with -2% is chosen, the output clock will range from 98 MHz to 100 MHz.

Figure 3-1 and Figure 3-2 show a spectrum example of the DSA612 with a 33.333 MHz clock, modulated with central spread of ±1%.

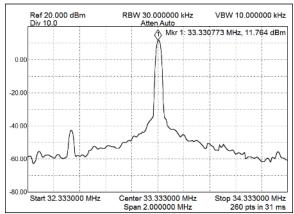


FIGURE 3-1: DSA612 Spectrum at 33.333 MHz with Modulation Turned Off.

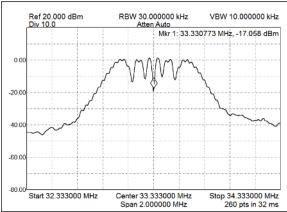


FIGURE 3-2: DSA612 Spectrum at 33.333 MHz with Modulation Turned On.

It is noticeable that the spread spectrum provides a reduction of about 10 dB from the peak power. Such a reduction may also be estimated by the following equation:

EQUATION 3-1:

 $EMI \ \ Reduction = 10 \times Log \ 10 (|S| \times fc \div RBW)$ Where: $S \quad Peak-to-peak \ spread \ percentage \ (0.01, \\ this \ example).$ $fc \quad Carrier \ frequency \ (33.333 \ MHz, this \\ example).$ $RBW \quad Resolution \ bandwidth \ of \ the \ spectrum \\ analyzer \ (30 \ kHz, this \ example).$

The theoretical calculation for this example provides 10.45 dB, which is consistent with the measurement.

Similarly to the fundamental frequency, all the harmonics are spread and attenuated in similar fashion. Figure 3-3 shows how the DSA612 fundamental at 33.333 MHz and its odd harmonics are attenuated when various types of modulations are selected. For picture clarity, only the center spread options are shown. However, down spread with corresponding percentage provides the same level of harmonic attenuation (e.g. central spread of $\pm 1\%$ provides the same harmonics attenuation of down spread with -2%).

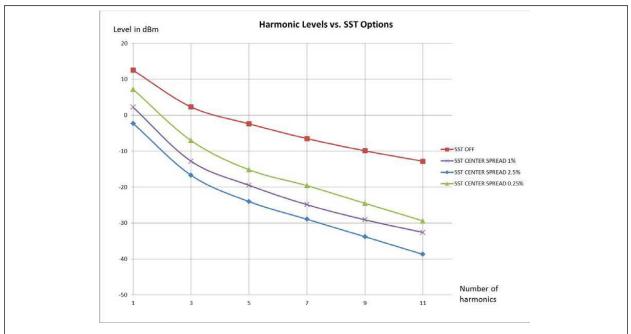


FIGURE 3-3: DSA612 Harmonic Levels with Various Spread Spectrum Options.

Visit Microchip's ClockWorks Configurator to select Spread Spectrum options.

4.0 OUTPUT WAVEFORM

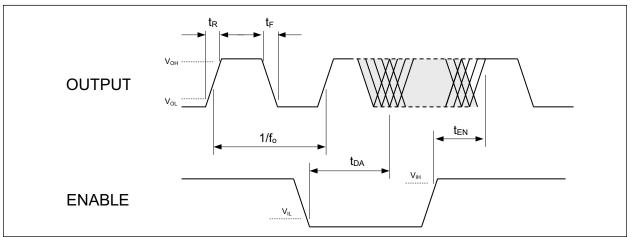


FIGURE 4-1: DSA612 Output Waveform.

5.0 BOARD LAYOUT

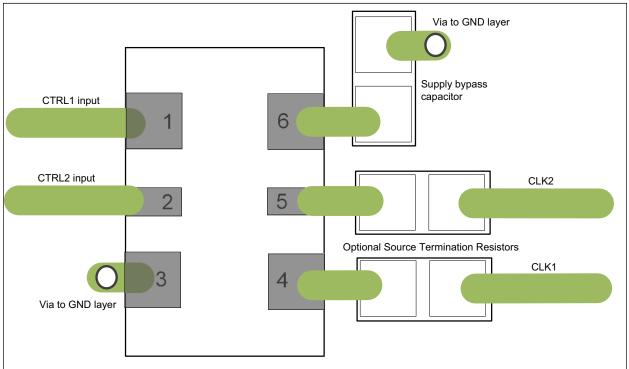


FIGURE 5-1: DSA612 Board Layout.

6.0 SOLDER REFLOW PROFILE

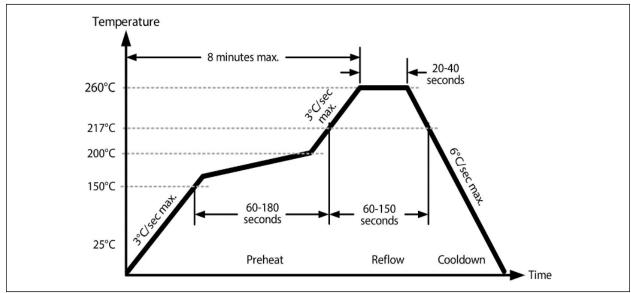


FIGURE 6-1: Solder Reflow Profile.

TABLE 6-1: SOLDER REFLOW

MSL 1 @ 260°C Refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp.)	3°C/sec. max.					
Preheat Time 150°C to 200°C	60 to 180 sec.					
Time Maintained above 217°C	60 to 150 sec.					
Peak Temperature	255°C to 260°C					
Time within 5°C of Actual Peak	20 to 40 sec.					
Ramp-Down Rate	6°C/sec. max.					
Time 25°C to Peak Temperature	8 minutes max.					

7.0 PACKAGING INFORMATION

7.1 Package Marking Information

6-Lead VFLGA* (2.5mm x 2.0mm)

XXXX DCPYYWW 0SSS

6-Lead VFLGA* (1.2mm x 1.6mm) (1.6mm x 2.0mm)

XXXX • SSS Example

0024 DCP1721 0K17

Example

00AE ■ D13

Legend: XX...X Product code or customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC® designator for Matte Tin (Sn)

This package is Pb-free. The Pb-free JEDEC designator (e3)

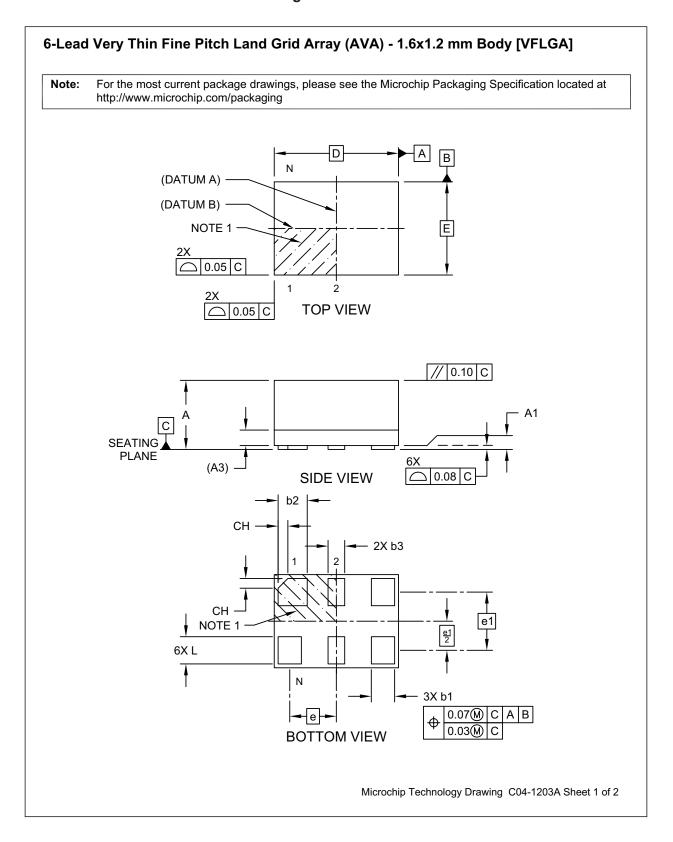
can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

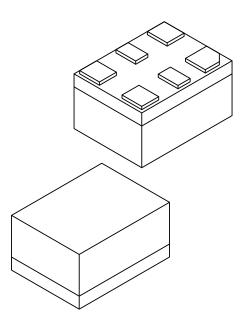
Underbar () and/or Overbar () symbol may not be to scale.

6-Lead 1.6 mm x 1.2 mm VFLGA Package Outline and Recommended Land Pattern



6-Lead Very Thin Fine Pitch Land Grid Array (AVA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		6	
Terminal Pitch	е		0.60 BSC	
Terminal Pitch	e1		0.75 BSC	
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		1.60 BSC	
Overall Width	Е		1.20 BSC	
Terminal Width	b1	0.25	0.30	0.35
Terminal Width	b2	0.325	0.375	0.425
Terminal Width	b3	0.20	0.25	0.30
Terminal Length	L	0.30 0.35 0.40		
Terminal 1 Index Chamfer	СН	-	0.125	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

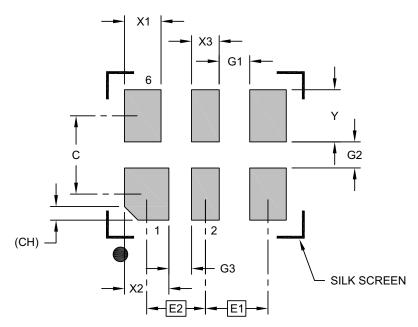
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1203A Sheet 2 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (AVA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units			
Dimension	MIN	NOM	MAX	
Contact Pitch (X3)	E1		0.60 BSC	
Contact Pitch	E2		0.56 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2	2		0.43
Contact Width (X2)	X3			0.27
Contact Pad Length (X6)	Υ	0.50		
Space Between Contacts (X4)	G1	0.29		
Space Between Contacts (X3)	G2	0.25		
Space Between Contacts	G3	0.22		
Contact 1 Index Chamfer	CH	0	.13 X 45° RE	F

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

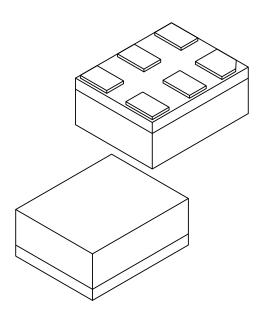
Microchip Technology Drawing C04-3203A

6-Lead 2.0 mm x 1.6 mm VFLGA Package Outline and Recommended Land Pattern

6-Lead Very Thin Fine Pitch Land Grid Array (ATA) - 2.0x1.6 mm Body [VFLGA] For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging (DATUM A) (DATUM B) NOTE 1 ○ 0.05 C **TOP VIEW** 0.05 C 0.10 C Α1 C A **SEATING PLANE** (A3) -0.08 C SIDE VIEW b2 CH NOTE 1 <u>e1</u> 2 6XL Ν 5X b1 **⊸**e → |0.07∭|C|A|B| 0.03(M)**BOTTOM VIEW** Microchip Technology Drawing C04-1201A Sheet 1 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (ATA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Number of Terminals	N		6	
Terminal Pitch	е		0.775 BSC	
Terminal Pitch	e1		0.95 BSC	
Overall Height	Α	0.79 0.84 0.89		
Standoff	A1	0.00 0.02 0.05		
Substrate Thickness (with Terminals)	A3		0.20 REF	
Overall Length	D		2.00 BSC	
Overall Width	Е		1.60 BSC	
Terminal Width	b1	0.30 0.35 0.40		
Terminal Width	b2	0.40 0.45 0.50		
Terminal Length	L	0.50 0.55 0.60		
Terminal 1 Index Chamfer	СН	-	0.15	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

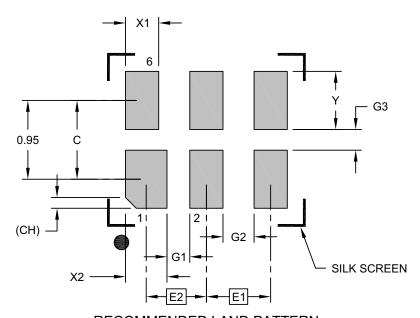
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1201A Sheet 2 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (ATA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	N	/ILLIMETER	S		
Dimension	MIN	NOM	MAX		
Contact Pitch	E1		0.78 BSC		
Contact Pitch	E2		0.73 BSC		
Contact Spacing	С	0.95			
Contact Width (X4)	X1	0.40			
Contact Width (X2)	X2	0.45			
Contact Pad Length (X6)	Υ			0.70	
Space Between Contacts (X4)	G1	0.28			
Space Between Contacts (X3)	G2	0.38			
Space Between Contacts (X3)	G3	0.25			
Contact 1 Index Chamfer	CH	0	0.13 X 45° REF		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

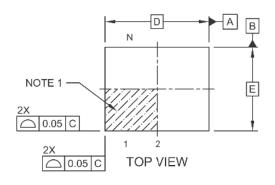
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

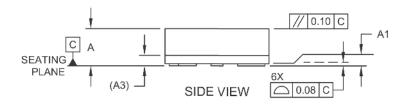
Microchip Technology Drawing C04-3201A

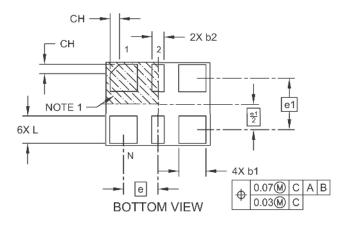
6-Lead 2.5 mm x 2.0 mm VFLGA Package Outline and Recommended Land Pattern

6-Lead Very Thin Fine Pitch Land Grid Array (AWA) - 2.5x2.0 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



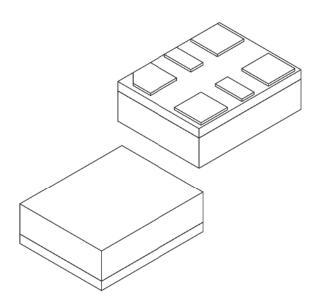




Microchip Technology Drawing C04-01204 Rev C Sheet 1 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (AWA) - 2.5x2.0 mm Body [VFLGA]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	N	ILLIMETER:	S	
Dimension	MIN	NOM	MAX	
Number of Terminals	Ν		6	
Terminal Pitch	е		0.825 BSC	
Terminal Pitch	e1		1.25 BSC	
Overall Height	Α	0.79 0.84 0.89		
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		2.50 BSC	
Overall Width	Е		2.00 BSC	
Terminal Width	b1	0.60	0.65	0.70
Terminal Width	b2	0.25	0.30	0.35
Terminal Length	L	0.60	0.65	0.70
Terminal 1 Index Chamfer	CH	-	0.225	-

Notes:

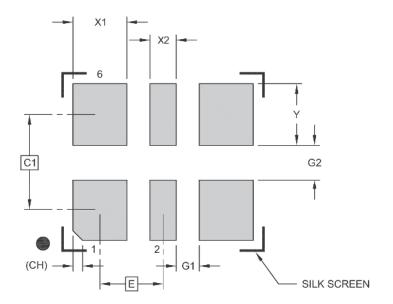
- Pin 1 visual index feature may vary, but must be located within the hatched area.
 Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-01204 Rev C Sheet 2 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (AWA) - 2.5x2.0 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS				
Dimension	MIN	MON	MAX		
Contact Pitch	E	0.825 BSC			
Contact Spacing	С	1.25 BSC			
Contact Width (X4)	X1	0.70			
Contact Width (X2)	X2	0.35			
Contact Pad Length (X6)	Υ		0.80		
Space Between Contacts (X4)	G1	0.30			
Space Between Contacts (X3)	G2	G2 0.45			
Contact 1 Index Chamfer	CH	0.13 X 45° REF			

Notes:

Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-03204 Rev C

DSA612

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (October 2019)

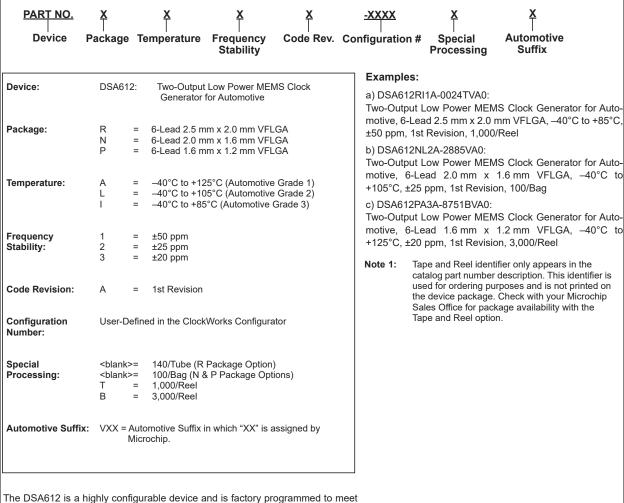
• Initial release of DSA612 as Microchip data sheet DS20006263A.

DSA612

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.



The DSA612 is a highly configurable device and is factory programmed to meet the customer's needs. Microchip's ClockWorks Configurator must be used to choose the necessary options, create the final part number, data sheet, and order samples.

DSA612

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TempTrackr, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, Vite, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet logo, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2019, Microchip Technology Incorporated, All Rights Reserved.

ISBN: 978-1-5224-5116-7

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277

Technical Support: http://www.microchip.com/

support Web Address: www.microchip.com

Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Atlanta

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Dallas Addison, TX Tel: 972-818-7423

Fax: 972-818-2924

Novi, MI Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800 Raleigh, NC

Tel: 919-844-7510 New York, NY

Tel: 631-435-6000 San Jose, CA

Tel: 408-735-9110 Tel: 408-436-4270 **Canada - Toronto** Tel: 905-695-1980 Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

China - Beijing Tel: 86-10-8569-7000

China - Chengdu Tel: 86-28-8665-5511

China - Chongqing Tel: 86-23-8980-9588

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai Tel: 86-21-3326-8000

China - Shenyang Tel: 86-24-2334-2829

China - Shenzhen Tel: 86-755-8864-2200

China - Suzhou Tel: 86-186-6233-1526

China - Wuhan Tel: 86-27-5980-5300

China - Xian Tel: 86-29-8833-7252

China - Xiamen
Tel: 86-592-2388138

China - Zhuhai Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631

India - Pune Tel: 91-20-4121-0141

Japan - Osaka Tel: 81-6-6152-7160

Japan - Tokyo Tel: 81-3-6880- 3770

Korea - Daegu Tel: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila Tel: 63-2-634-9065

Singapore Tel: 65-6334-8870

Taiwan - Hsin Chu Tel: 886-3-577-8366

Taiwan - Kaohsiung Tel: 886-7-213-7830

Taiwan - Taipei Tel: 886-2-2508-8600

Thailand - Bangkok Tel: 66-2-694-1351

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

Finland - Espoo Tel: 358-9-4520-820

France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79

Germany - Garching Tel: 49-8931-9700

Germany - Haan Tel: 49-2129-3766400

Germany - Heilbronn Tel: 49-7131-72400

Germany - Karlsruhe Tel: 49-721-625370

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Rosenheim Tel: 49-8031-354-560

Israel - Ra'anana Tel: 972-9-744-7705

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Padova Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Norway - Trondheim Tel: 47-7288-4388

Poland - Warsaw Tel: 48-22-3325737

Romania - Bucharest Tel: 40-21-407-87-50

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820